



HMBTA06

NPN SILICON TRANSISTOR

Description

Amplifier Transistor

Absolute Maximum Ratings

- Maximum Temperatures
Storage Temperature..... -55 ~ +150 °C
Junction Temperature..... +150 °C Maximum
- Maximum Power Dissipation
Total Power Dissipation (T_A=25°C)..... 225 mW
- Maximum Voltages and Currents (T_A=25°C)
V_{CBO} Collector to Base Voltage..... 80 V
V_{CEO} Collector to Emitter Voltage 80 V
V_{EBO} Emitter to Base Voltage..... 4 V
I_C Collector Current..... 500 mA

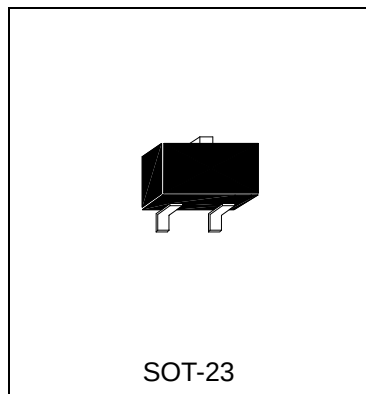
Thermal Characteristic

Symbol	Characteristic	Max.	Unit
R _{θja}	Thermal Resistance, junction to ambient (T _A =25°C)	556	°C/W

Electrical Characteristics (T_A=25°C)

Symbol	Min.	Typ.	Max.	Unit	Test Conditions
BV _{CBO}	80	-	-	V	I _C =100uA
BV _{CEO}	80	-	-	V	I _C =1mA
BV _{EBO}	4	-	-	V	I _E =100uA
I _{CBO}	-	-	100	nA	V _{CB} =80V
I _{CEO}	-	-	100	nA	V _{CE} =60V
*V _{CE(sat)}	-	-	0.25	V	I _C =100mA, I _B =10mA
V _{BE(on)}	-	-	1.2	V	I _C =100mA, V _{CE} =1V
*h _{FE1}	50	-	-		I _C =10mA, V _{CE} =1V
*h _{FE2}	50	-	-		I _C =100mA, V _{CE} =1V
f _T	100	-	-	MHz	I _C =10mA, V _{CE} =2V, f=100MHz

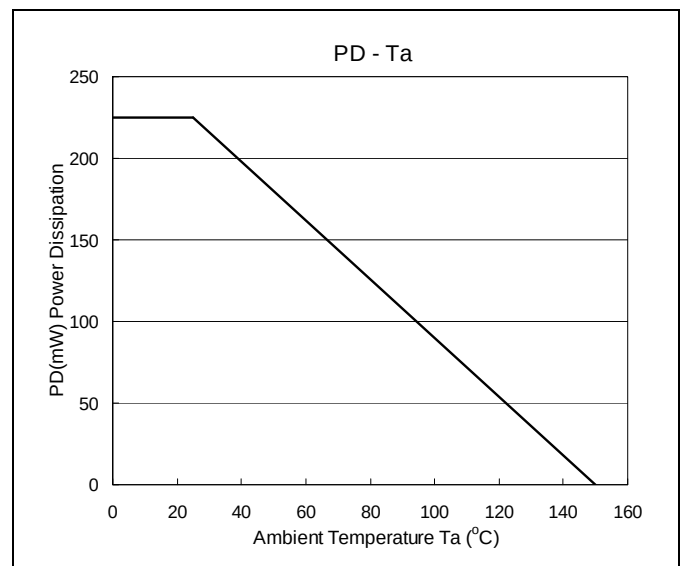
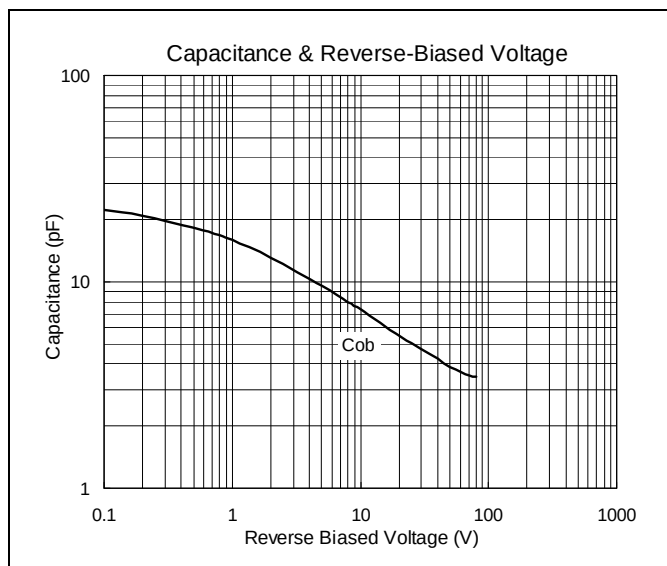
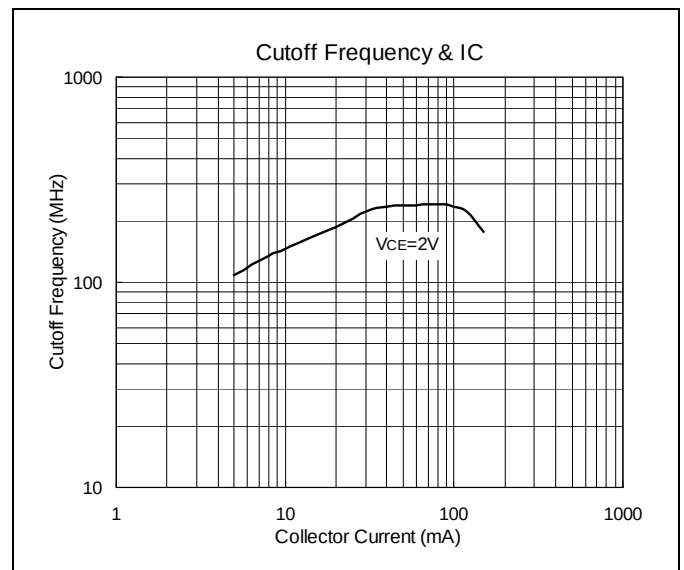
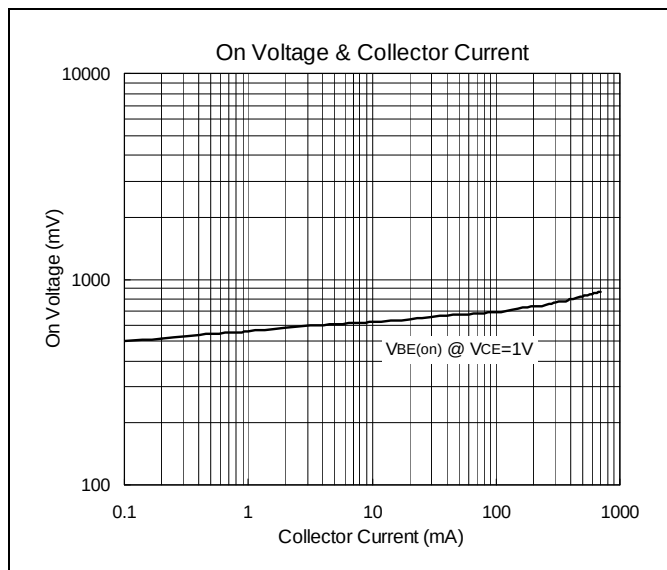
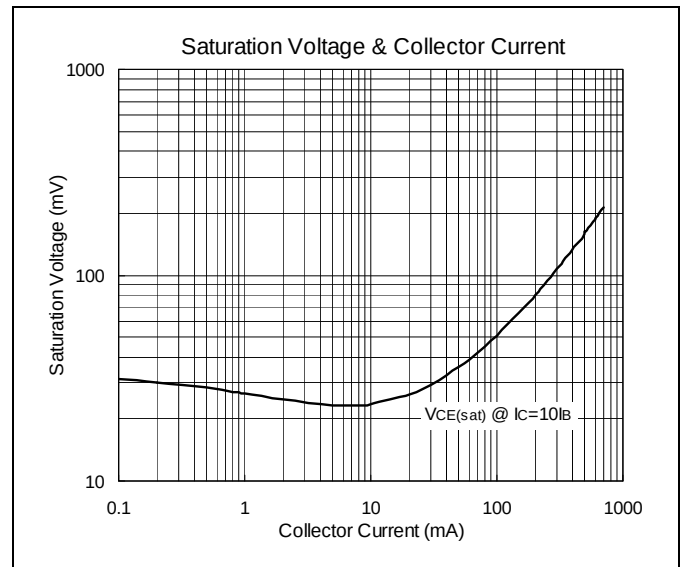
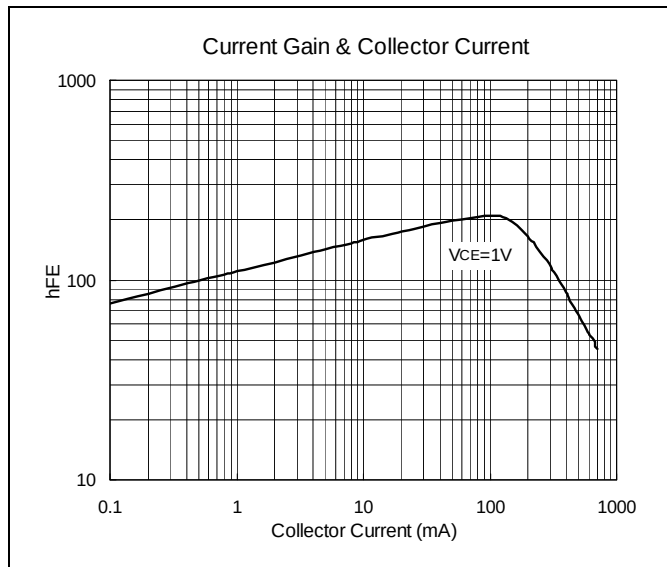
*Pulse Test: Pulse Width ≤380us, Duty Cycle≤2%



SOT-23

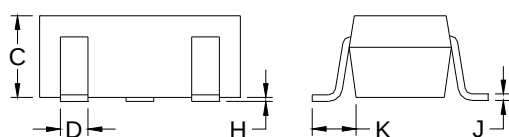
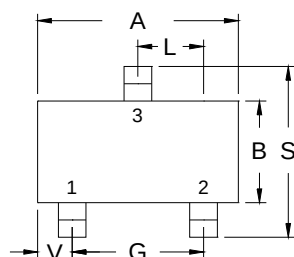


Characteristics Curve



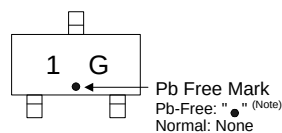


SOT-23 Dimension



3-Lead SOT-23 Plastic
Surface Mounted Package
HSMC Package Code: N

Marking:



Note: Pb-free product can distinguish by the green label or the extra description on the right side of the label.

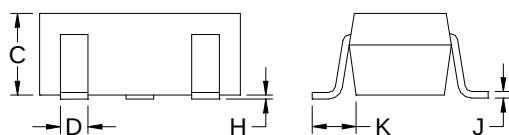
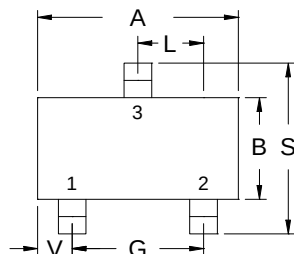
Pin Style: 1.Base 2.Emitter 3.Collector

Material:

- Lead solder plating: Sn60/Pb40 (Normal), Sn/3.0Ag/0.5Cu or Pure-Tin (Pb-free)
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0

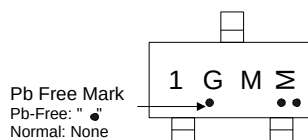
DIM	Min.	Max.
A	2.80	3.04
B	1.20	1.60
C	0.89	1.30
D	0.30	0.50
G	1.70	2.30
H	0.013	0.10
J	0.085	0.177
K	0.32	0.67
L	0.85	1.15
S	2.10	2.75
V	0.25	0.65

*: Typical, Unit: mm



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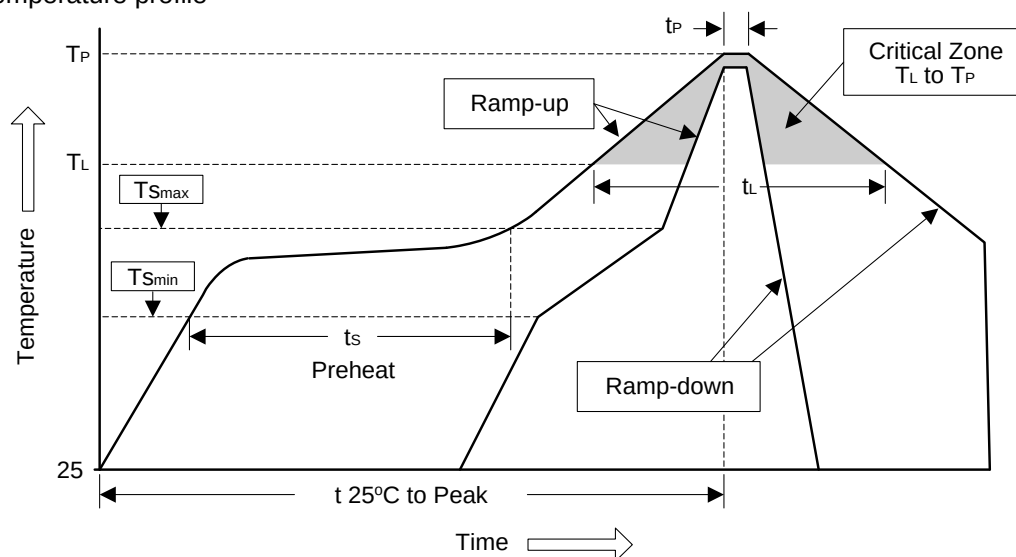
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Tel: 886-3-5983621~5 Fax: 886-3-5982931



Soldering Methods for HSMC's Products

1. Storage environment: Temperature=10°C~35°C Humidity=65%±15%
2. Reflow soldering of surface-mount devices

Figure 1: Temperature profile



Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Average ramp-up rate (T_L to T_P)	$<3^{\circ}\text{C}/\text{sec}$	$<3^{\circ}\text{C}/\text{sec}$
Preheat		
- Temperature Min (T_{Smin})	100°C	150°C
- Temperature Max (T_{Smax})	150°C	200°C
- Time (min to max) (t_s)	60~120 sec	60~180 sec
T_{Smax} to T_L		
- Ramp-up Rate	$<3^{\circ}\text{C}/\text{sec}$	$<3^{\circ}\text{C}/\text{sec}$
Time maintained above:		
- Temperature (T_L)	183°C	217°C
- Time (t_L)	60~150 sec	60~150 sec
Peak Temperature (T_P)	240°C +0/-5°C	260°C +0/-5°C
Time within 5°C of actual Peak Temperature (t_P)	10~30 sec	20~40 sec
Ramp-down Rate	$<6^{\circ}\text{C}/\text{sec}$	$<6^{\circ}\text{C}/\text{sec}$
Time 25°C to Peak Temperature	<6 minutes	<8 minutes

3. Flow (wave) soldering (solder dipping)

Products	Peak temperature	Dipping time
Pb devices.	245°C ±5°C	5sec ±1sec
Pb-Free devices.	260°C +0/-5°C	5sec ±1sec